

HD74ALVC1G32

2-input OR Gate

REJ03D0112-0600 Rev.6.00 Jun.20.2005

Description

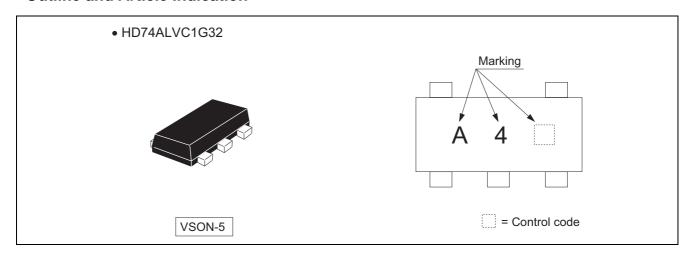
The HD74ALVC1G32 has two-input OR gate in a 5 pin package. Low voltage and high-speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

Features

- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- Supply voltage range : 1.2 to 3.6 V
 Operating temperature range : -40 to +85°C
- All inputs V_{IH} (Max.) = 3.6 V (@ V_{CC} = 0 V to 3.6 V) All outputs V_{O} (Max.) = 3.6 V (@ V_{CC} = 0 V)
- Output current ± 2 mA (@V_{CC} = 1.2 V) ± 4 mA (@V_{CC} = 1.4 V to 1.6 V) ± 6 mA (@V_{CC} = 1.65 V to 1.95 V) ± 18 mA (@V_{CC} = 2.3 V to 2.7 V) ± 24 mA (@V_{CC} = 3.0 V to 3.6 V)
- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
HD74ALVC1G32VSE	VSON-5 pin	PUSN0005KA-A (TNP-5DV)	VS	E (3,000 pcs/reel)

Outline and Article Indication

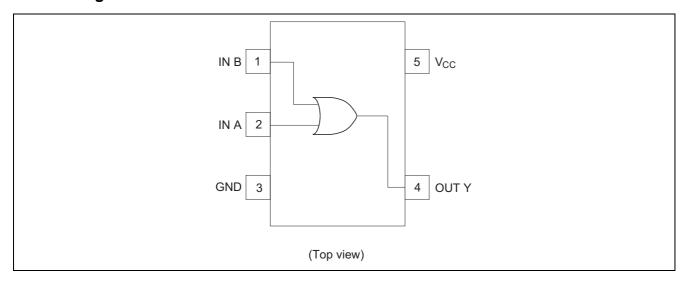


Function Table

Inp	Output	
A	В	Y
L	L	L
L	Н	Н
Н	L	Н
Н	Н	Н

H: High levelL: Low level

Pin Arrangement



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	V _{CC}	-0.5 to 4.6	V	
Input voltage range *1	Vı	-0.5 to 4.6	V	
Output voltage range *1,2	Vo	-0.5 to $V_{CC} + 0.5$	V	Output : H or L
		-0.5 to 4.6		V _{CC} : OFF
Input clamp current	I _{IK}	-50	mA	V _I < 0
Output clamp current	I _{OK}	±50	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	I _O	±50	mA	$V_O = 0$ to V_{CC}
Continuous current through V _{CC} or GND	I _{CC} or I _{GND}	±100	mA	
Maximum power dissipation at Ta = 25°C (in still air) *3	P _T	200	mW	
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- 2. This value is limited to 4.6 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

ltem	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V_{CC}	1.2	3.6	V	
Input voltage range	Vı	0	3.6	V	
Output voltage range	Vo	0	V _{CC}	V	
Output current	I _{OH}	_	-2	mA	V _{CC} = 1.2 V
		_	-4		V _{CC} = 1.4 V
		_	-6		V _{CC} = 1.65 V
		_	-18		V _{CC} = 2.3 V
		_	-24		V _{CC} = 3.0 V
	I _{OL}	_	2		V _{CC} = 1.2 V
		_	4		V _{CC} = 1.4 V
		_	6		V _{CC} = 1.65 V
		_	18		V _{CC} = 2.3 V
		_	24		V _{CC} = 3.0 V
Input transition rise or fall rate	Δt / Δν	0	20	ns / V	V _{CC} = 1.2 to 2.7 V
		0	10		V _{CC} = 3.3±0.3 V
Operating free-air temperature	Та	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

Electrical Characteristics

 $Ta = -40 \text{ to } 85^{\circ}\text{C}$

Item	Symbol	V _{CC} (V) *	Min	Тур	Max	Unit	Test condition
Input voltage	V _{IH}	1.2	V _{CC} ×0.75	_	_	V	
		1.4 to 1.6	V _{CC} ×0.7	_	_		
		1.65 to 1.95	V _{CC} ×0.7	_	_		
		2.3 to 2.7	1.7		_		
		3.0 to 3.6	2.0		_		
	V_{IL}	1.2	_		V _{CC} ×0.25		
		1.4 to 1.6	_		V _{CC} ×0.3		
		1.65 to 1.95	_	_	V _{CC} ×0.3		
		2.3 to 2.7	_		0.7		
		3.0 to 3.6	_	_	0.8		
Output voltage	V _{OH}	Min to Max	V _{CC} -0.2		_	V	$I_{OH} = -100 \mu A$
		1.2	0.9		_		$I_{OH} = -2 \text{ mA}$
		1.4	1.1	_	_		$I_{OH} = -4 \text{ mA}$
		1.65	1.2		_		$I_{OH} = -6 \text{ mA}$
		2.3	1.7		_		$I_{OH} = -18 \text{ mA}$
		3.0	2.2	_	_		$I_{OH} = -24 \text{ mA}$
	V_{OL}	Min to Max	_		0.2		$I_{OL} = 100 \mu A$
		1.2	_		0.3		I _{OL} = 2 mA
		1.4	_	_	0.3		$I_{OL} = 4 \text{ mA}$
		1.65	_		0.3		I _{OL} = 6 mA
		2.3	_		0.55		I _{OL} = 18 mA
		3.0	_		0.55		I _{OL} = 24 mA
Input current	I _{IN}	3.6	_	_	±5	μΑ	V _{IN} = 3.6 V or GND
Quiescent	Icc	3.6	_		10	μΑ	$V_{IN} = V_{CC}$ or GND, $I_O = 0$
supply current							
Output leakage	I _{OFF}	0	_	_	5	μΑ	V_1 or $V_0 = 0$ to 3.6 V
current							
Input capacitance	C _{IN}	3.3	_	4.5	_	pF	$V_{IN} = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

Switching Characteristics

$V_{\rm CC} = 1.2 \ V$

		Ta = -40 to 85°C			Test	FROM	ТО	
Item	Symbol	Min	Тур	Max	Unit	Conditions	(Input)	(Output)
Propagation delay time	t _{PLH}	_	7.5	_	ns	C _L = 15 pF	A or B	Υ
	t _{PHL}							

$V_{CC}=1.5\pm0.1~V$

		Ta = -40 to 85°C			Test	FROM	ТО	
Item	Symbol	Min	Тур	Max	Unit	Conditions	(Input)	(Output)
Propagation delay time	t _{PLH} t _{PHL}	2.0	_	7.0	ns	$C_L = 15 pF$	A or B	Υ

$V_{CC}=1.8\pm0.15~V$

		Ta = -40 to 85°C			Test	FROM	ТО	
Item	Symbol	Min	Тур	Max	Unit	Conditions	(Input)	(Output)
Propagation delay time	t _{PLH} t _{PHL}	1.5	_	5.0	ns	C _L = 30 pF	A or B	Υ

$V_{CC}=2.5\pm0.2\ V$

		Ta = -40 to 85°C				Test	FROM	ТО
Item	Symbol	Min	Тур	Max	Unit	Conditions	(Input)	(Output)
Propagation delay time	t _{PLH} t _{PHL}	1.0	_	3.7	ns	$C_L = 30 pF$	A or B	Υ

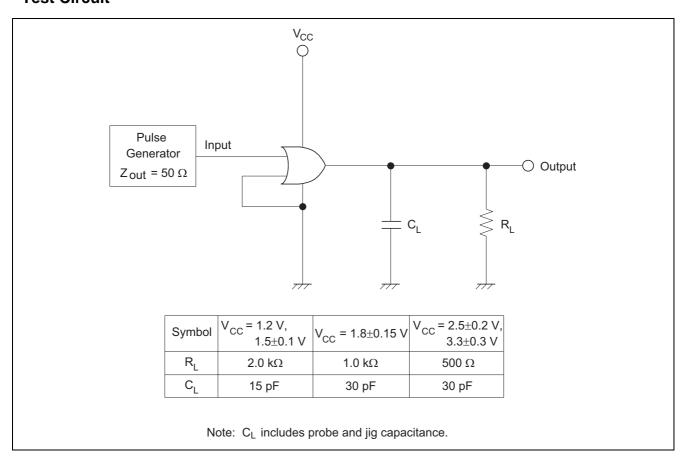
$$V_{CC} = 3.3 \pm 0.3 \text{ V}$$

		Ta = -40 to 85°C			Test	FROM	ТО	
Item	Symbol	Min	Тур	Max	Unit	Conditions	(Input)	(Output)
Propagation delay time	t _{PLH}	1.0	_	2.8	ns	$C_L = 30 pF$	A or B	Υ

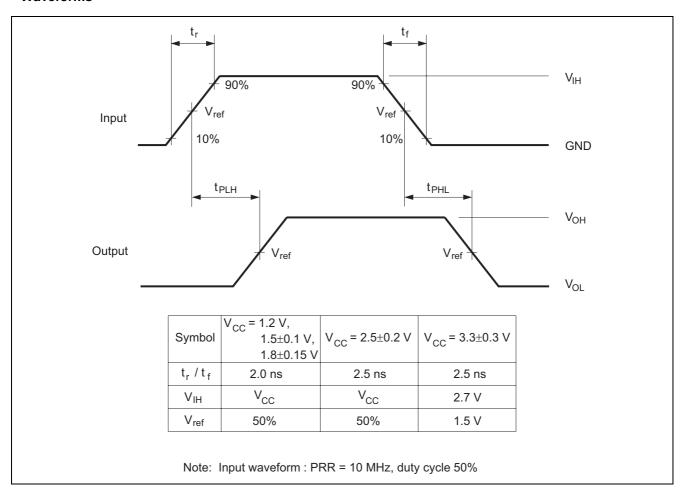
Operating Characteristics

				Ta = 25°C			
Item	Symbol	V _{CC} (V)	Min	Тур	Max	Unit	Test Conditions
Power dissipation	C _{PD}	1.5	_	10.5	_	pF	f = 10 MHz
capacitance		1.8	_	10.5	_		
		2.5	_	10.5	_		
		3.3	_	11.5	_		

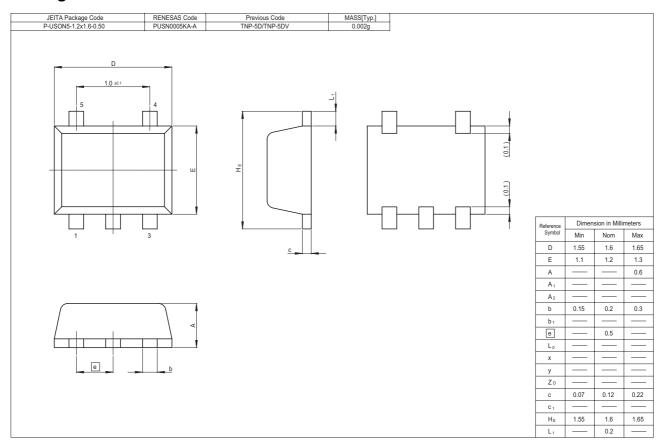
Test Circuit



Waveforms



Package Dimensions



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